

E1

DATE 23 OCT 2015

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF b DIMENSION AT MAXIMUM MATERIAL CONDITION.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- PROTRUSIONS.

 5. MAXIMUM MOLD PROTRUSION OR FLASH TO
- BE 0.15 PER SIDE.

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.35	2.65	
A1	0.00	0.10	
b	0.35	0.49	
С	0.25	0.32	
D	10.15	10.45	
D1	1.79	2.00	
Е	7.40	7.60	
E1	2.27	2.47	
е	1.27 BSC		
Н	10.05	10.55	
h	0.53 REF		
L	0.50	0.90	
M	0°	7°	

GENERIC MARKING DIAGRAM*



= Specific Device Code = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week = Pb-Free Package

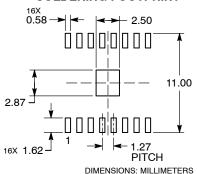
XXX

Α

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

RECOMMENDED SOLDERING FOOTPRINT

BOTTOM VIEW



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DESCRIPTION:	SOIC-16 WB, EP		PAGE 1 OF 1

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